

Environmental Sensitivity of a Radiation Sensitive Semiconducting Polymer

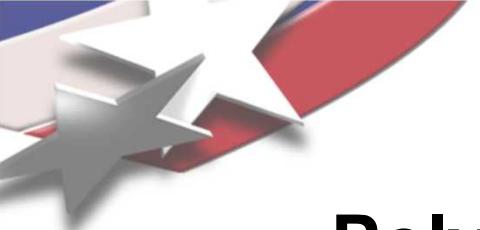
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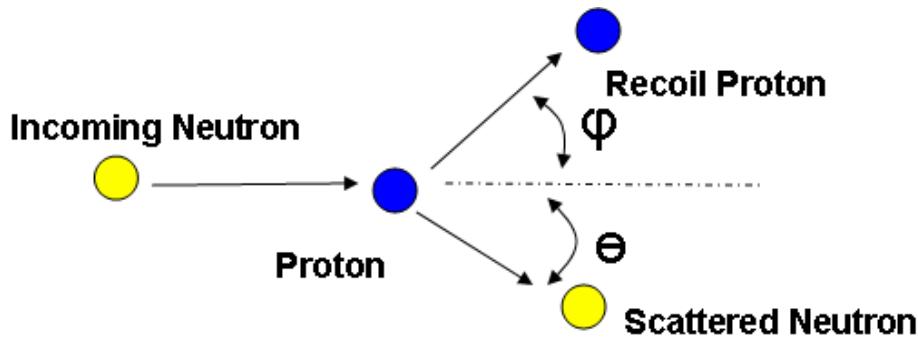


Polymer Radiation Detection - Why?

- Semiconducting radiation detectors allow detection with no photomultiplier, as required with scintillators
- Polymer detector allows direct detection of fast neutrons (2 MeV), with no moderator
- Room temperature operation improves cost, size and convenience
- Low Z polymer provides minimal gamma interaction
- High H/C ratio for neutron sensitivity
- High Dielectric strength – Can operate at high field
- Low Dielectric constant – low capacitance
- High Resistivity – low leakage current



Polymer Radiation Sensors – How?

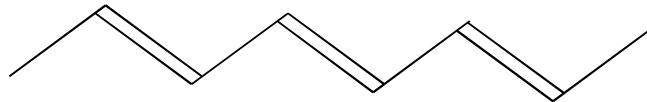


- Proton recoil reaction
- Proton excites mobile charged particles → detection
- Charges transported by imposed bias

- We Need
 - High mobility
 - High resistivity
 - Thickness (high H density per unit area)
 - Low trapping and recombination
- Controlled by
 - Chemistry
 - Processing
 - Additives
 - Environment



Conjugated Polymer Conduction



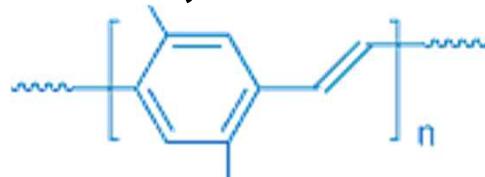
- Conductivity from insulator to metallic (after doping)
- $\pi - \pi^*$ energy gap E_g is typically 1.5 - 3 eV
- Upon photoexcitation of a polymer, a neutral exciton is formed
- Charge separation by electron transfer to an adjacent chain, resulting in positive and negative polarons on separate chains
- Charges can then be transported to electrodes with an imposed bias
- Recombination and trapping can reduce charge collection
- Excitation by ionizing radiation likely proceeds along a similar pathway
- Typically hopping transport, field and temperature dependant

$$\mu_h(E, T) \propto \exp(-\Delta/kT) \cdot \exp(\beta\sqrt{E}/kT)$$



Poly(p-phenylene vinylene), PPV

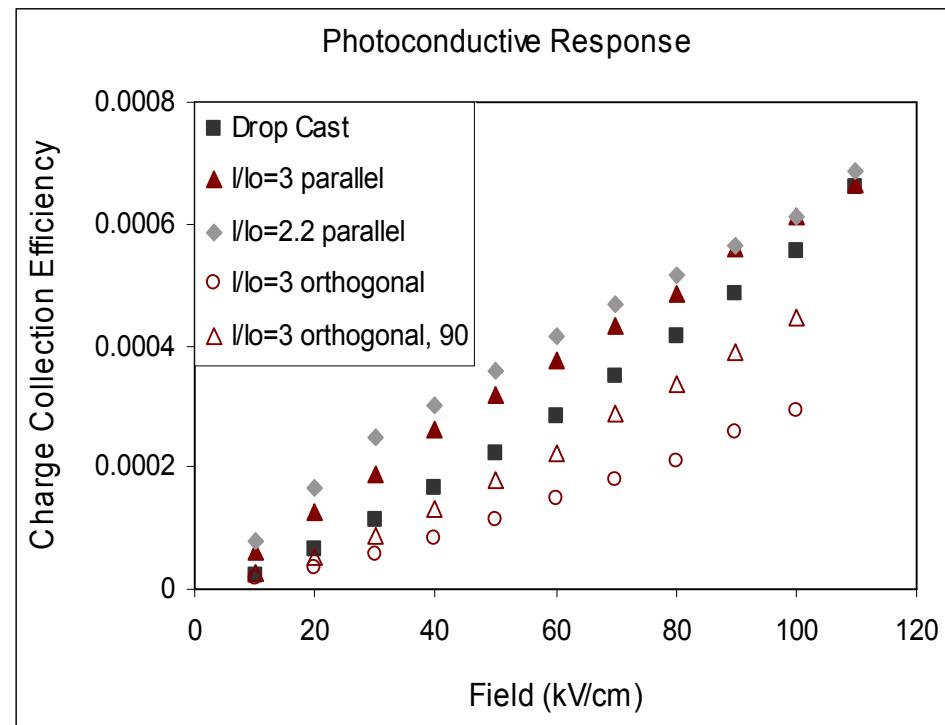
- I have chosen to work with the family of PPVs
- PPVs have mobilities typically from $\sim 10^{-5} - 10^{-2} \text{ cm}^2/\text{Vs}$
(Si $\sim 500 \text{ cm}^2/\text{Vs}$; SiO₂ $\sim 30 \text{ cm}^2/\text{Vs}$)



- **Workable air stability – easier processing**
- **Properties dependant on many variables**
 - Side chain symmetry
 - Solvent, concentration
 - Deposition method and conditions
 - Post-Deposition processing – vapor, anneal, stretch
 - Additives – nanoparticles and plasticizers

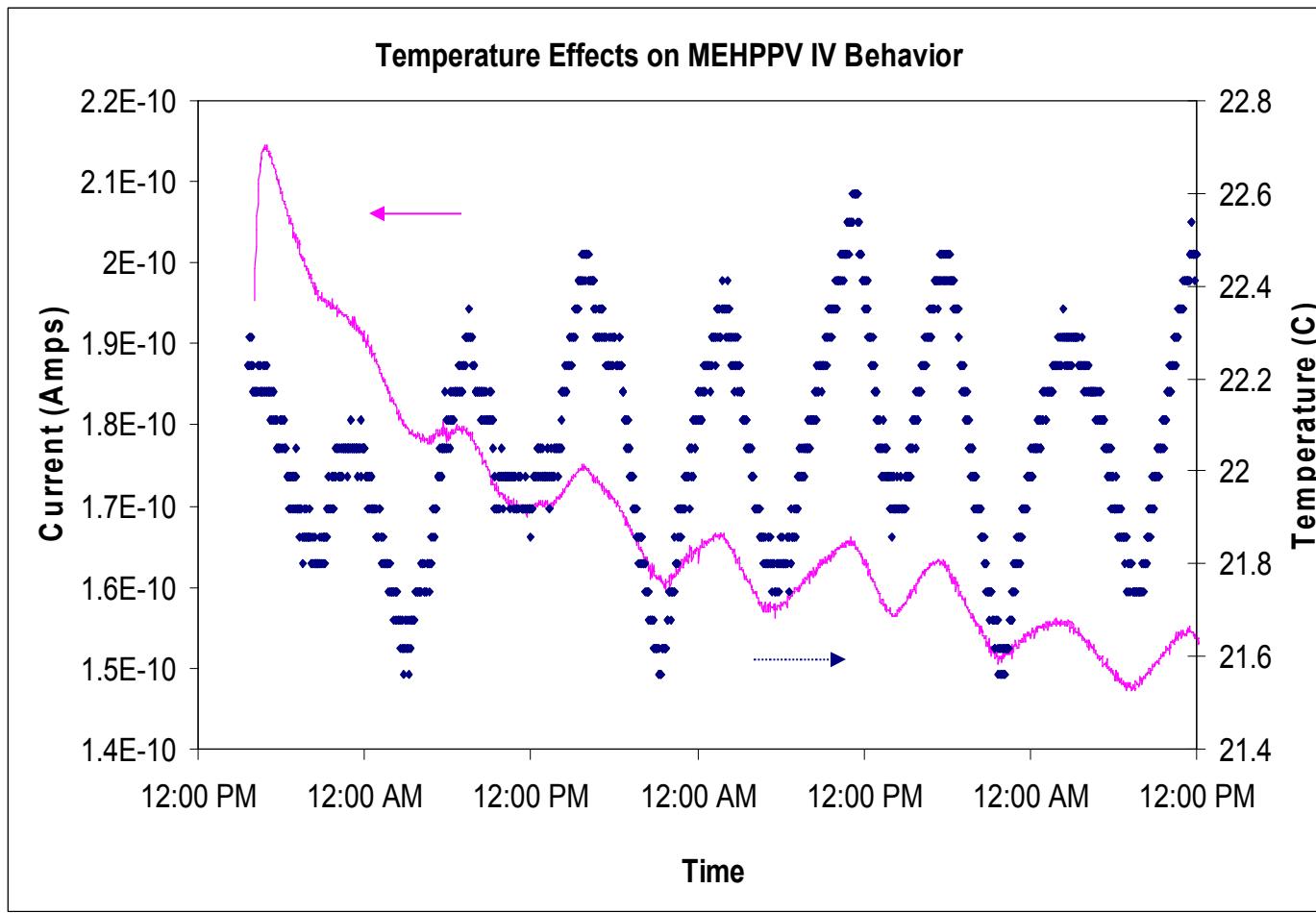
Previous Work

- **Demonstrated radiation sensitivity**
- **Showed increase in photoconductivity with certain processing variables**
- **Current work examines relevant environmental variables**



T. M. S. Wilson, F. P. Doty, D. A. Chinn, M. J. King and B. A. Simmons, "Order and Charge Collection Correlations in Organic Materials for Neutron Detection," in *Penetrating Radiation Systems and Applications VIII*. F. Patrick Doty, Hans Roehrig, Ed., p. 670710, SPIE, San Diego, CA (2007).

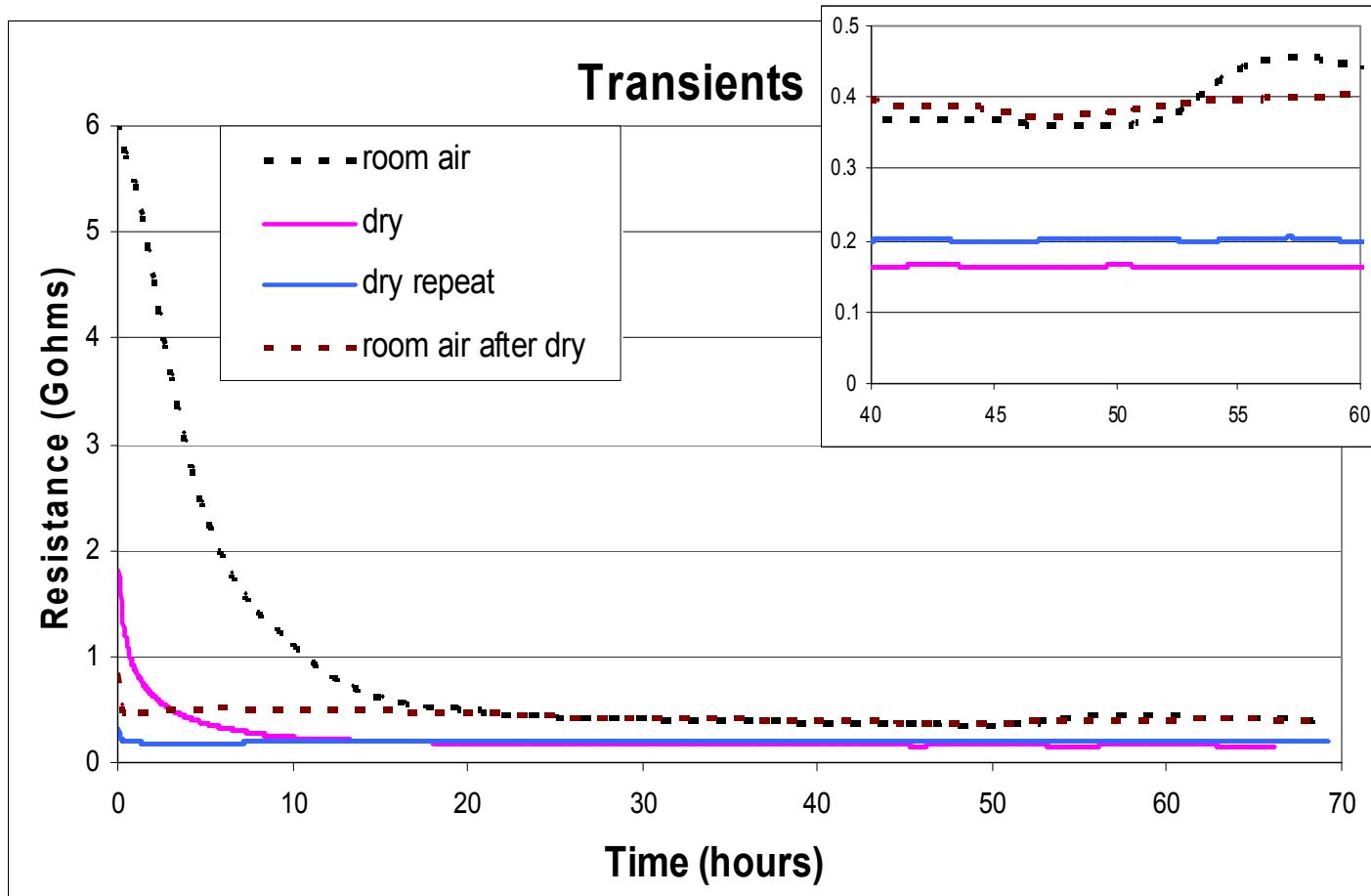
Temperature Dependence



- 1 °C variation in room temperature causes 10 pA change in current
- Temperature sensitivity expected, but not this extreme
- Possible complication
- Possible sensor application

Moisture

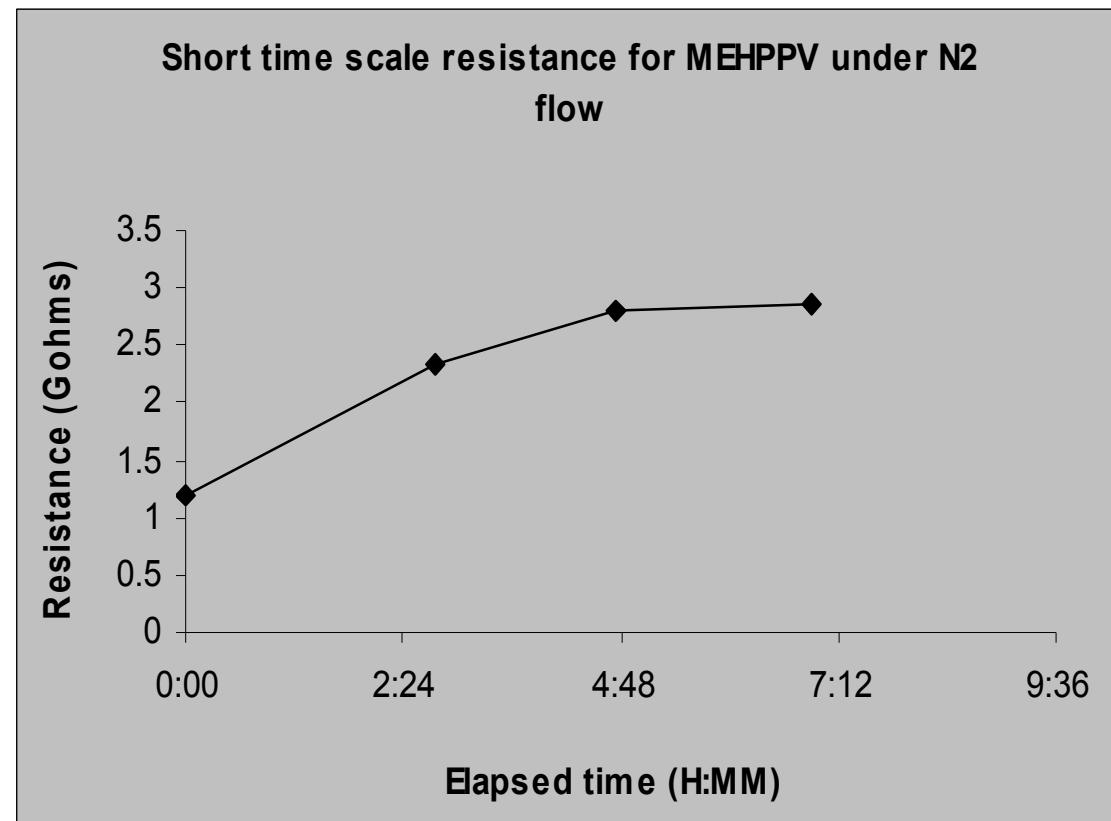
- Air v dry air
- Sample in dry air shows roughly 1/2 the resistivity of the sample in room air after equilibration (0.2 GΩ in dry air vs 0.4 GΩ in room air)
- Completely reversible





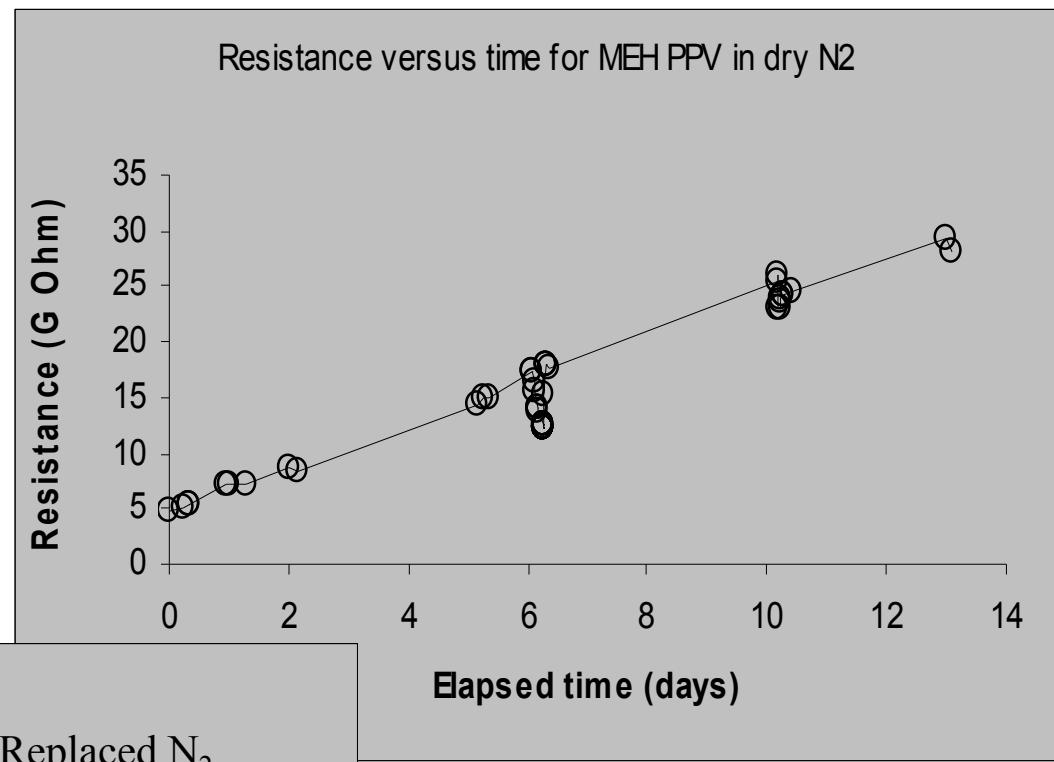
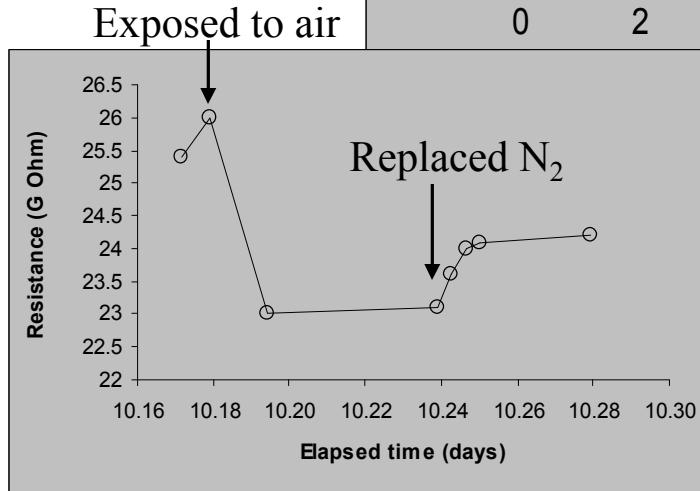
Nitrogen Purge

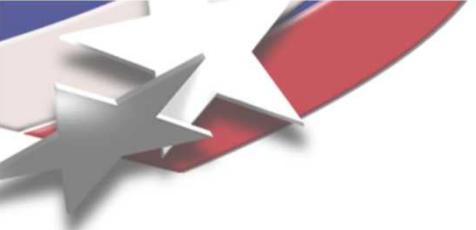
- Began purge with dry nitrogen and monitored resistance across interdigitated electrode over time
- Resistance quickly doubled in a matter of a few hours under purge



Effects of Air/Oxygen

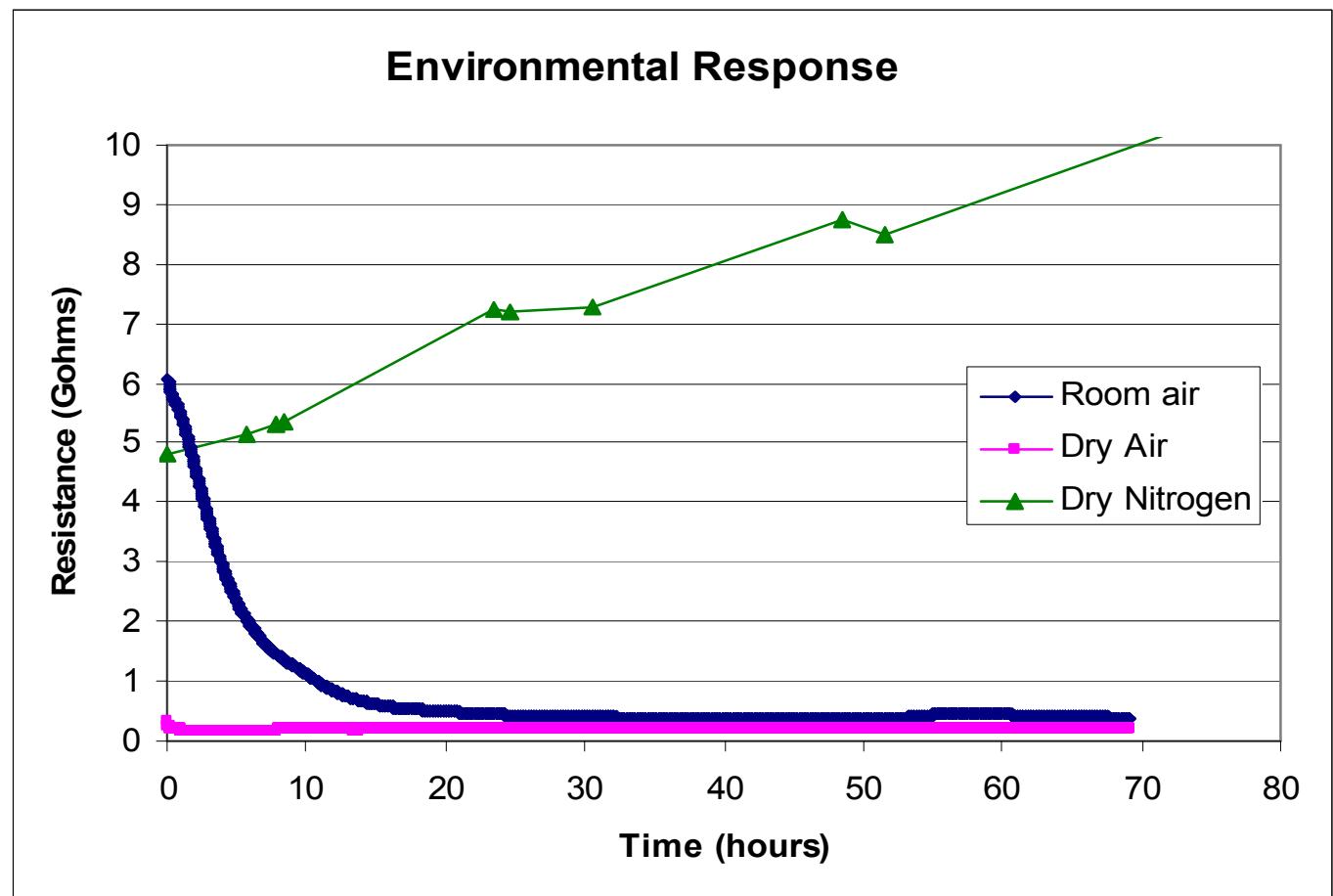
- Not simple diffusion effects
- Resistance decrease upon removal of N₂ purge and air exposure is very fast (.18 Gohm/ min)
- Resistance increase under purge is much slower (.05 Gohm/ min)



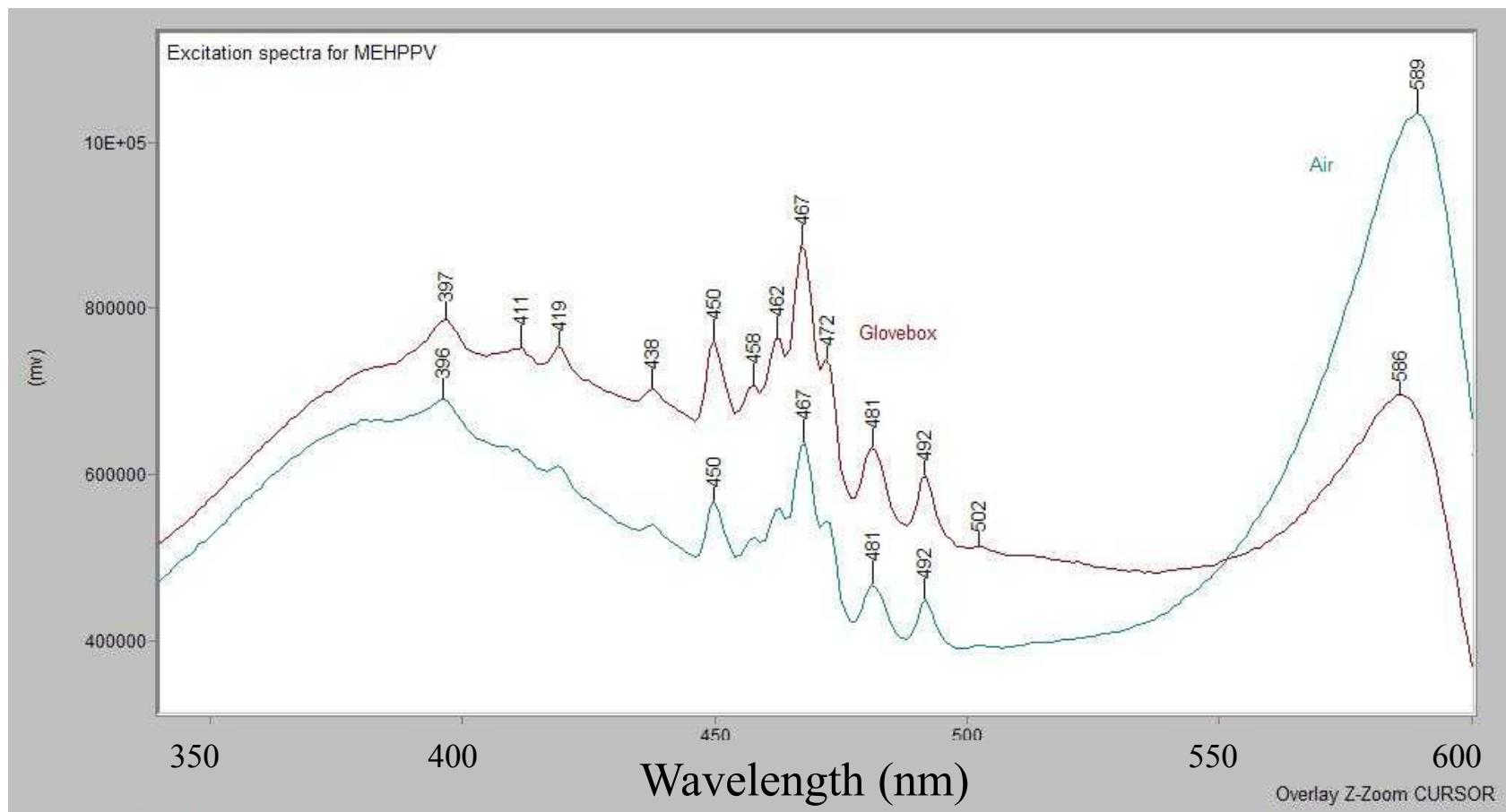


Environment Summary

- Complex Interactions
- Humidity
- Oxygen
- Other factors possible

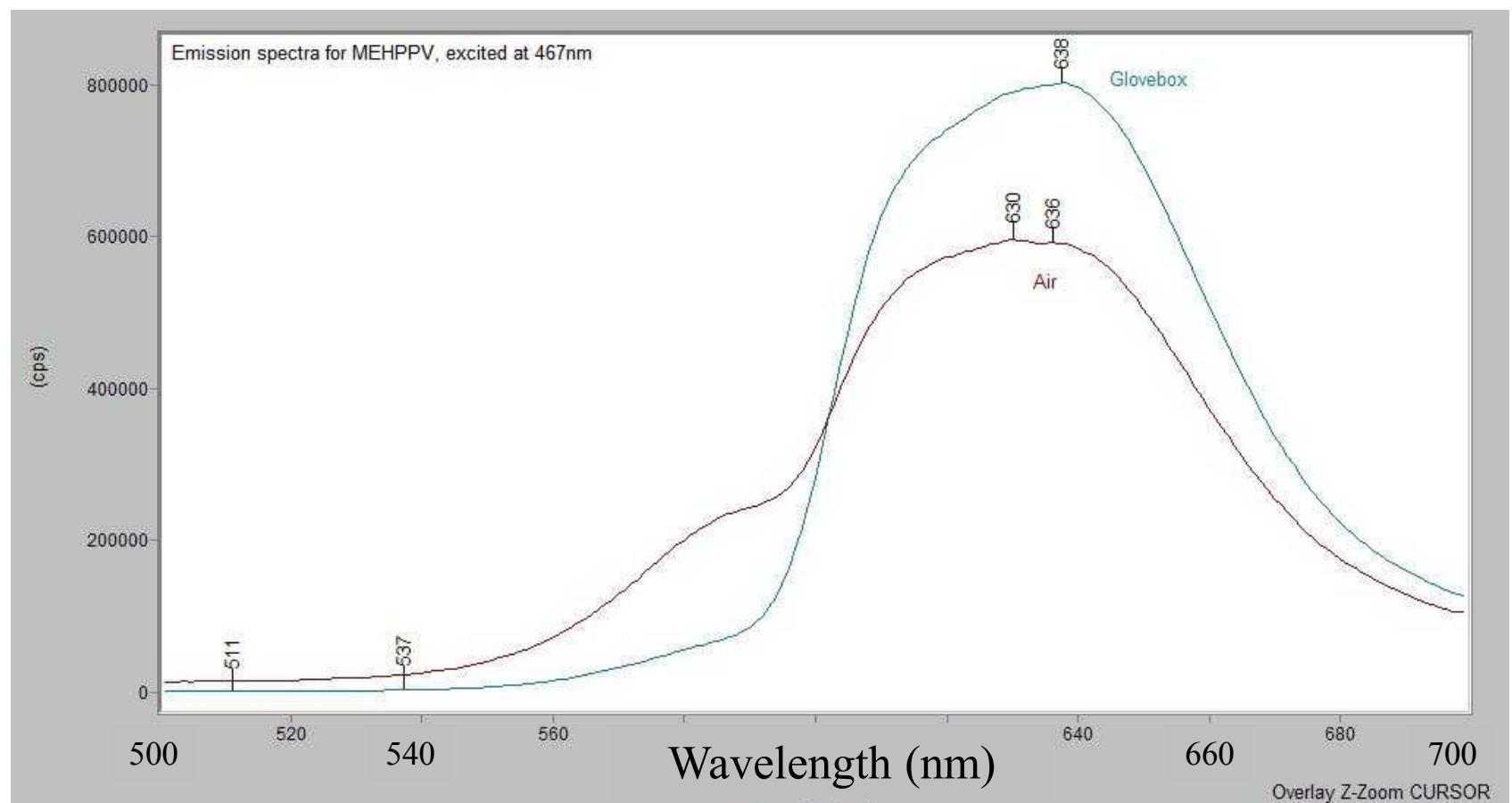


Excitation/Emission



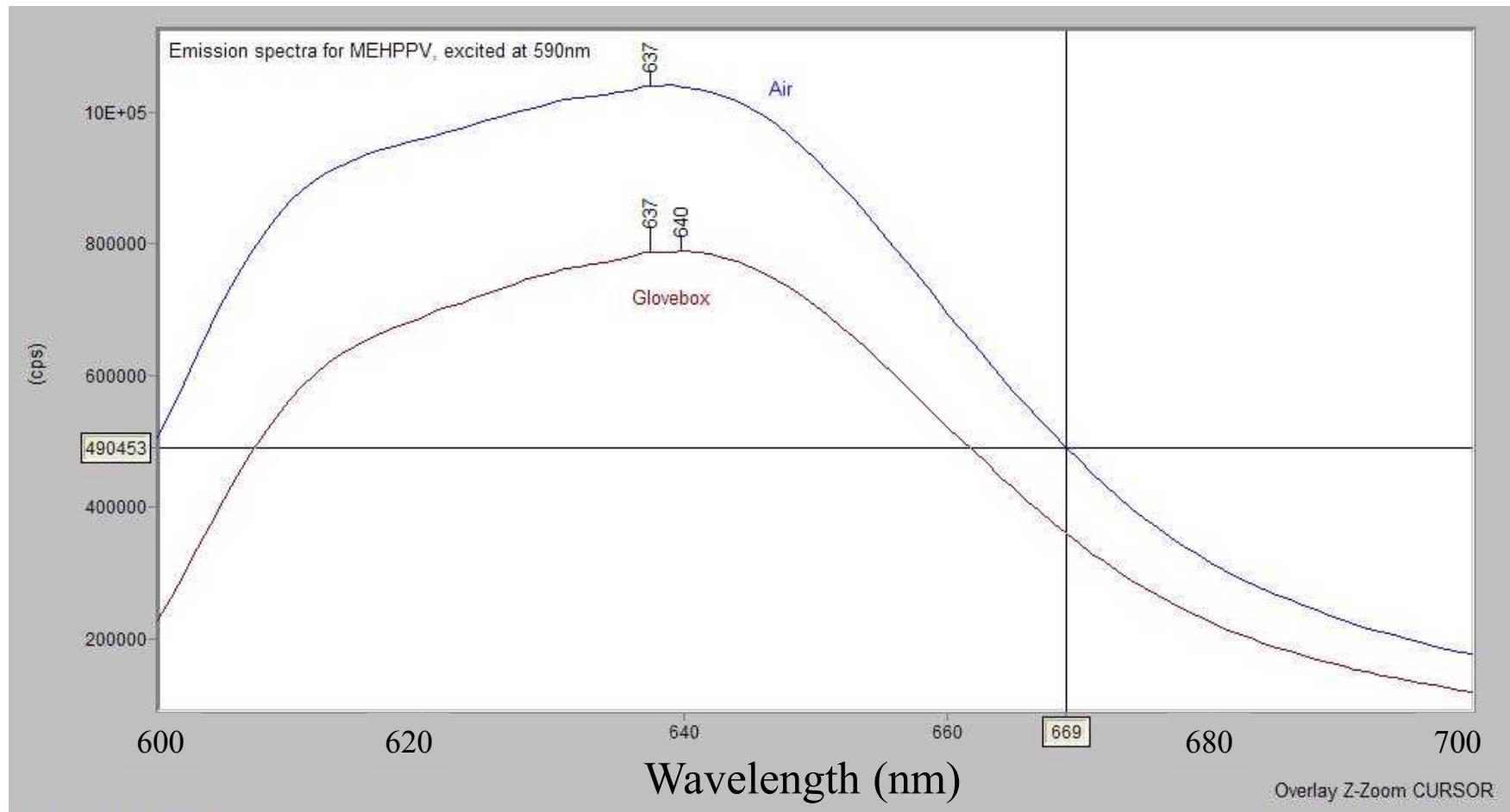
Excitation spectra

Excitation/Emission



Emission spectra, excited at 467 nm

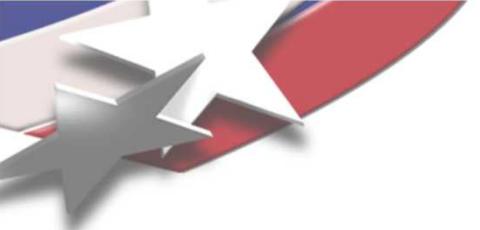
Excitation/Emission





Conclusions

- Previous work showed the possibility of using conjugated polymers as ionizing radiation detectors, and showed improvements in sensitivity with processing parameters and additives
- This work shows possible complications due to environmental sensitivity
- Environment needs to be considered for other experimental work using these materials
- Environmental sensitivity also opens the door to use these materials as sensors



Acknowledgements

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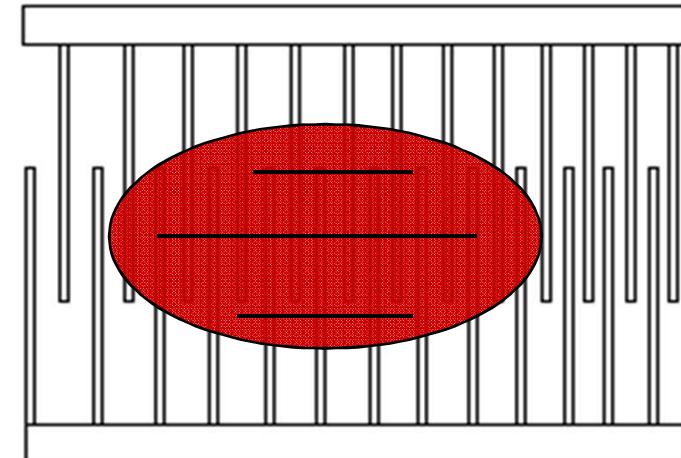
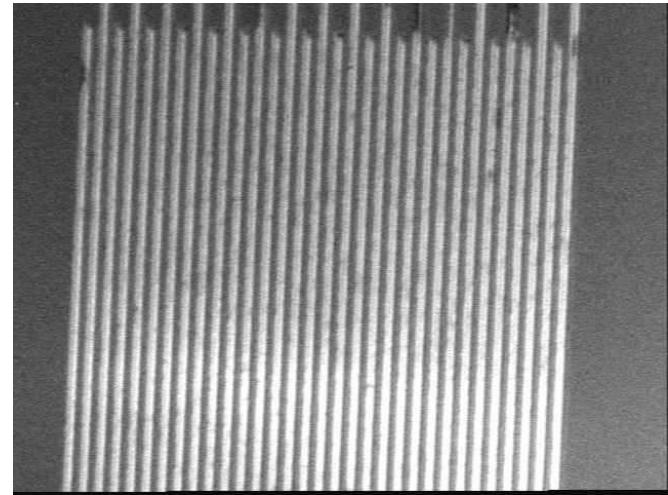


Supplemental Materials



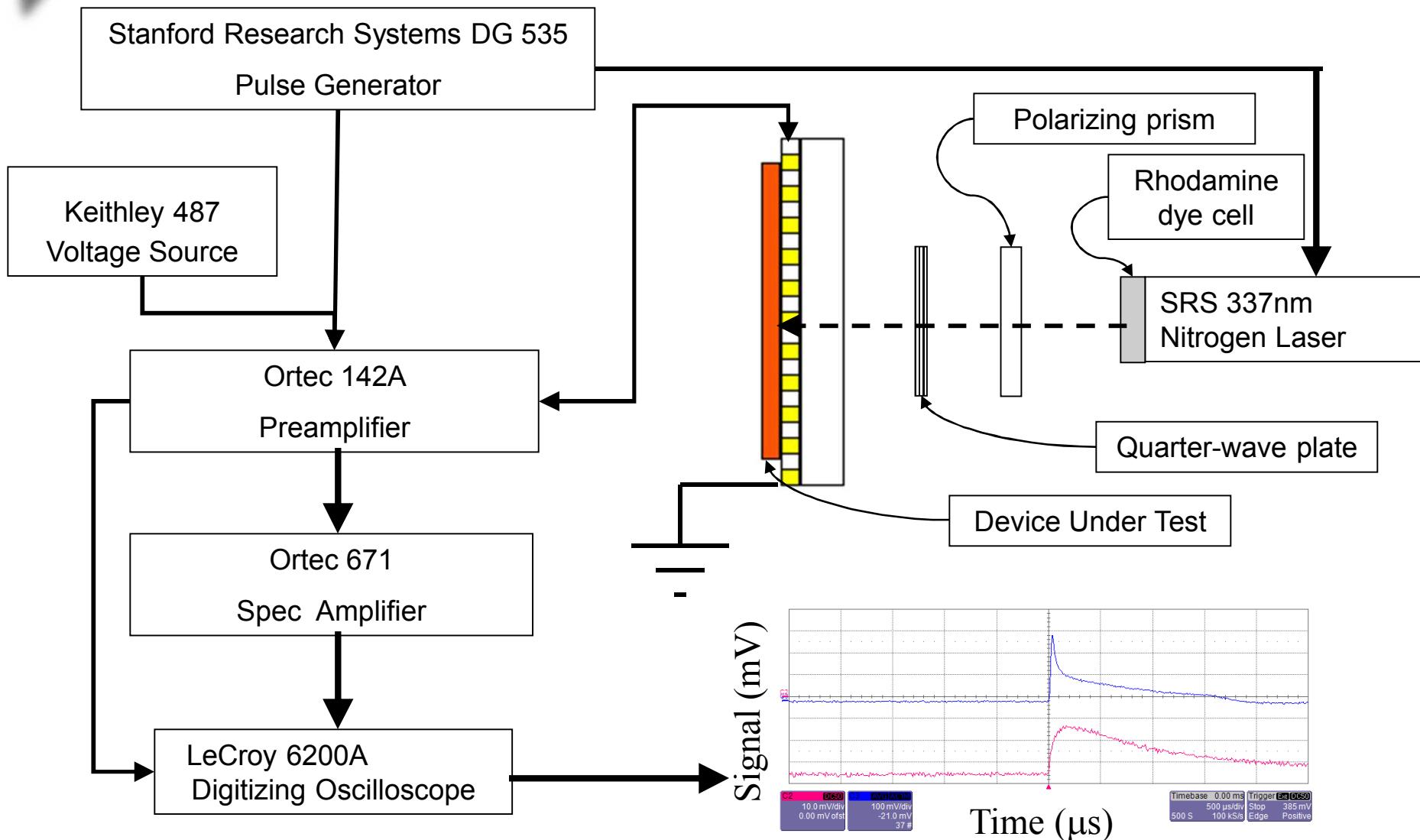
Electrical Testing

- **Interdigitated electrodes (IDEs)**
- **Gap of 4 - 64 μm , typically 16 μm**
- **Bias between electrodes**
- **Can orient film for bias to be parallel or perpendicular to the orientation direction**
- **Can also directly apply solution with no orientation**

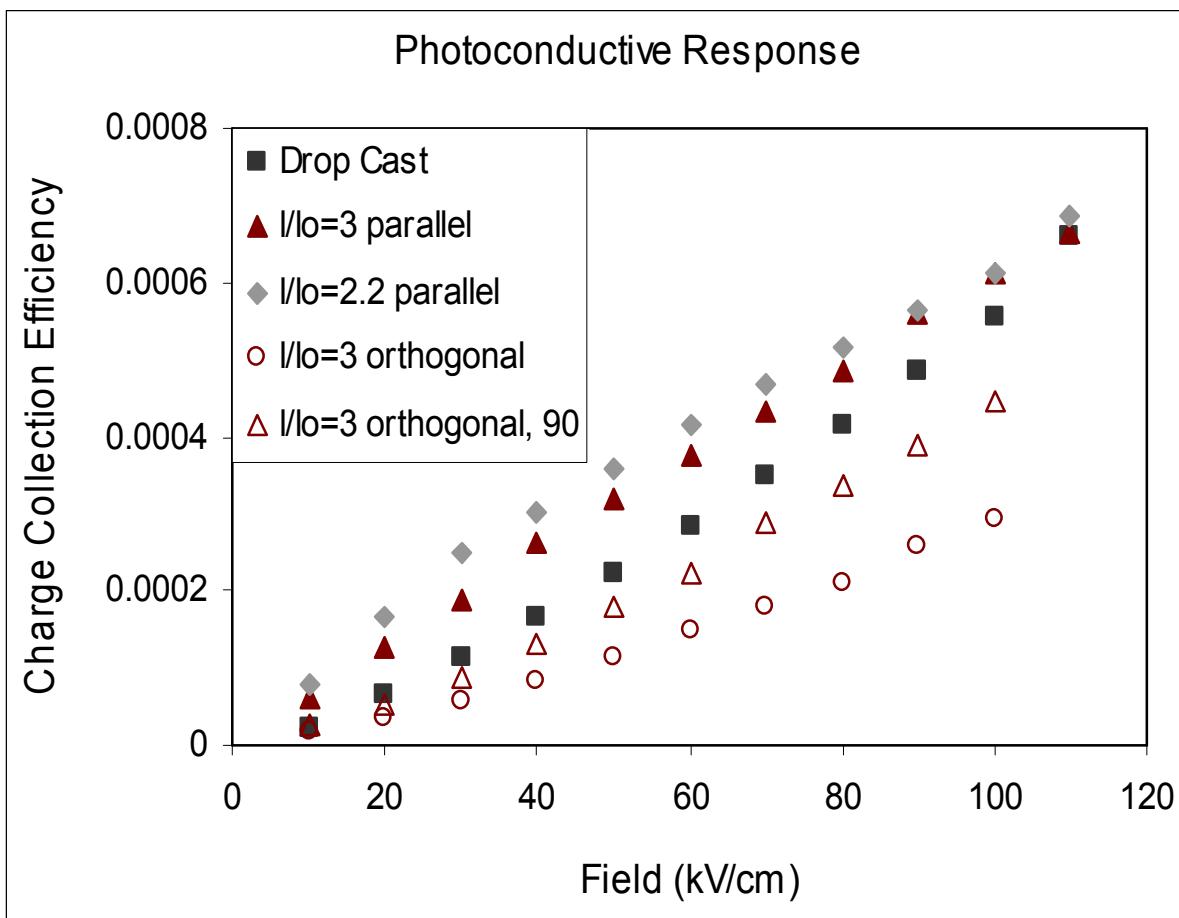


Parallel Orientation

Pulsed Photoconductivity setup



Stretched v. Drop-Cast



- Drop Cast v. Stretched to $I/I_0=2.2, 3$
- 16 μm IDTs
- 581nm pulsed laser
- Stretched samples shows increased photoconductive response in one direction, decreased in orthogonal direction
- Possible plateau effect